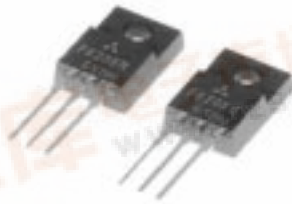


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HIGH-SPEED SWITCHING USE

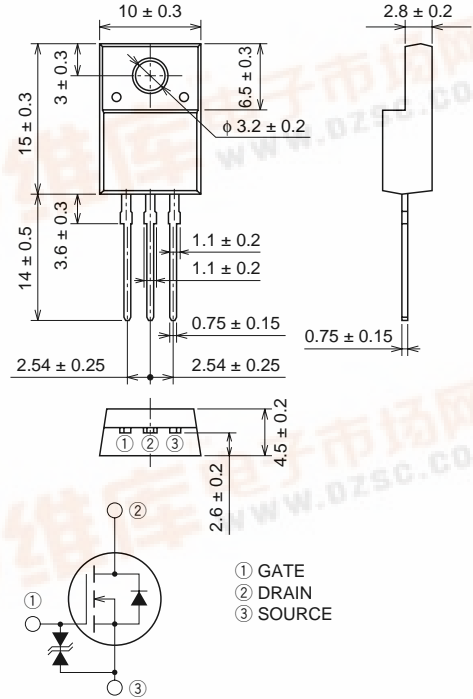
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- V_{DSS} 300V
- r_{DS (ON)} (MAX) 0.33Ω
- I_D 20A
- V_{iso} 2000V
- Integrated Fast Recovery Diode (MAX.) 150ns

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

Servo motor drive, Robot, UPS, Inverter Fluorecent lamp, etc.

MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-source voltage	V _{GS} = 0V	300	V
V _{GSS}	Gate-source voltage	V _{DS} = 0V	±30	V
I _D	Drain current		20	A
I _{DM}	Drain current (Pulsed)		60	A
I _S	Source current		20	A
I _{SM}	Source current (Pulsed)		60	A
P _D	Maximum power dissipation		40	W
T _{ch}	Channel temperature		-55 ~ +150	°C
T _{stg}	Storage temperature		-55 ~ +150	°C
V _{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V _{rms}
—	Weight	Typical value	2.0	g

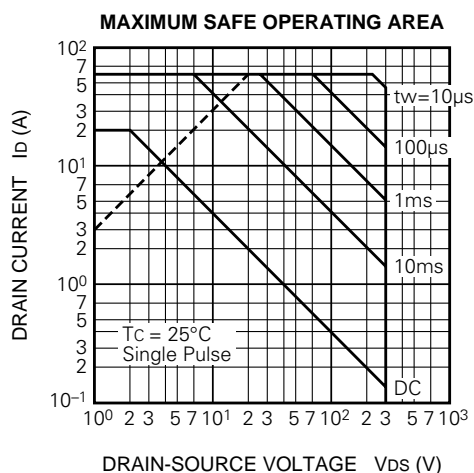
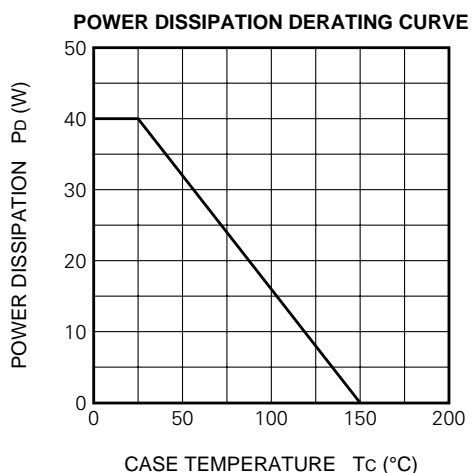
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HIGH-SPEED SWITCHING USE

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	ID = 1mA, VGS = 0V	300	—	—	V
V (BR) GSS	Gate-source breakdown voltage	IG = ±100μA, VDS = 0V	±30	—	—	V
IGSS	Gate-source leakage current	VGS = ±25V, VDS = 0V	—	—	±10	μA
IDSS	Drain-source leakage current	VDS = 300V, VGS = 0V	—	—	1	mA
VGS (th)	Gate-source threshold voltage	ID = 1mA, VDS = 10V	2	3	4	V
rDS (ON)	Drain-source on-state resistance	ID = 10A, VGS = 10V	—	0.25	0.33	Ω
VDS (ON)	Drain-source on-state voltage	ID = 10A, VGS = 10V	—	2.5	3.3	V
yfs	Forward transfer admittance	ID = 10A, VDS = 10V	8.5	13.0	—	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	1400	—	pF
Coss	Output capacitance		—	280	—	pF
Crss	Reverse transfer capacitance		—	55	—	pF
td (on)	Turn-on delay time	VDD = 150V, ID = 10A, VGS = 10V, RGEN = RGS = 50Ω	—	25	—	ns
tr	Rise time		—	50	—	ns
td (off)	Turn-off delay time		—	150	—	ns
tf	Fall time		—	65	—	ns
VSD	Source-drain voltage	IS = 10A, VGS = 0V	—	1.5	2.0	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	3.13	°C/W
trr	Reverse recovery time	IS = 20A, dis/dt = -100A/μs	—	—	150	ns

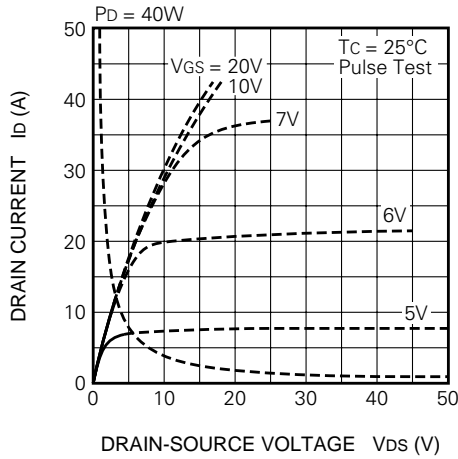
PERFORMANCE CURVES



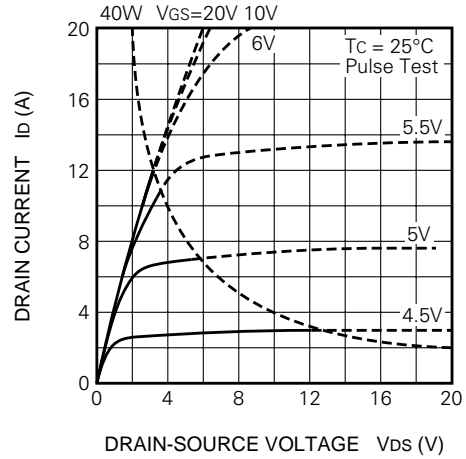
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HIGH-SPEED SWITCHING USE

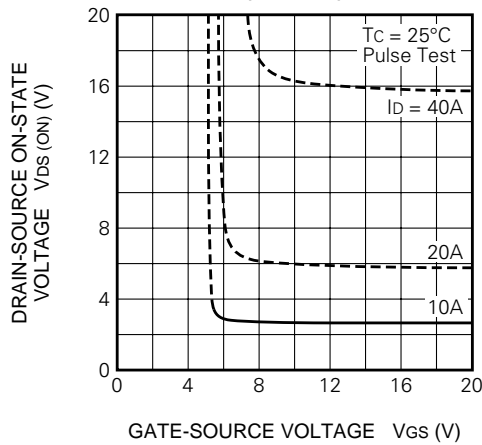
OUTPUT CHARACTERISTICS (TYPICAL)



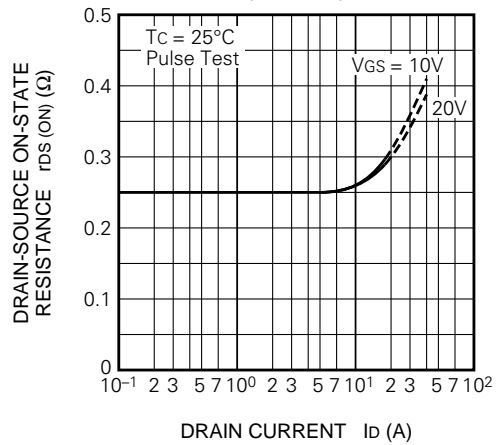
OUTPUT CHARACTERISTICS (TYPICAL)



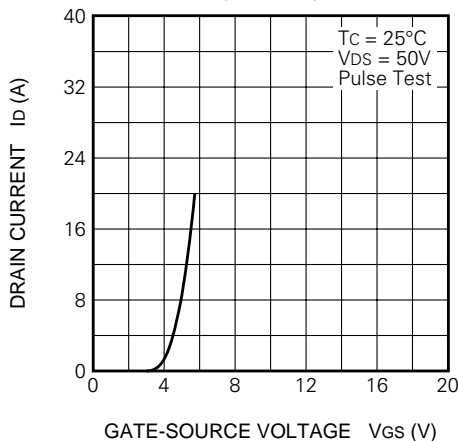
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



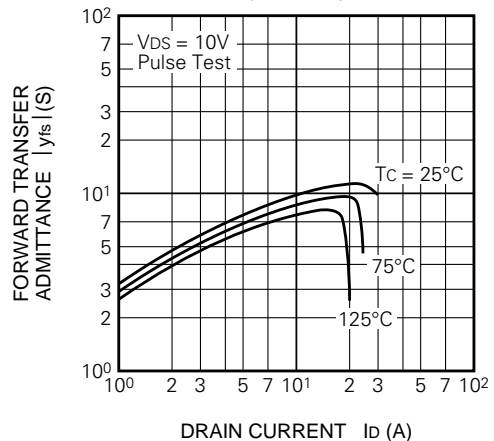
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



TRANSFER CHARACTERISTICS (TYPICAL)



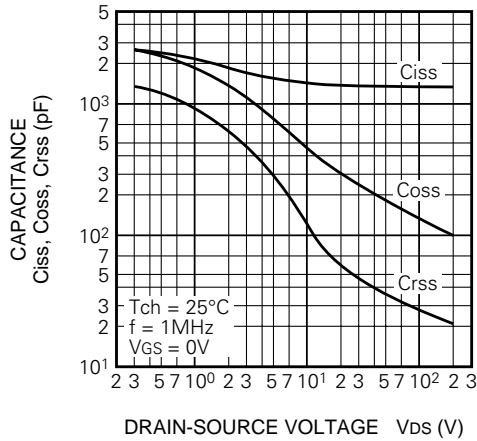
FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



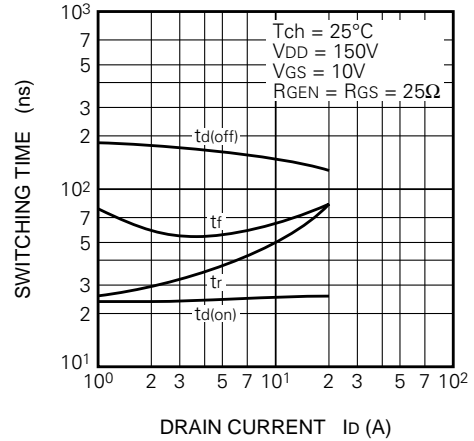
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HIGH-SPEED SWITCHING USE

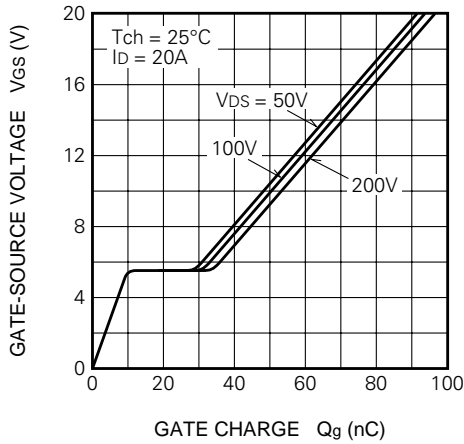
CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



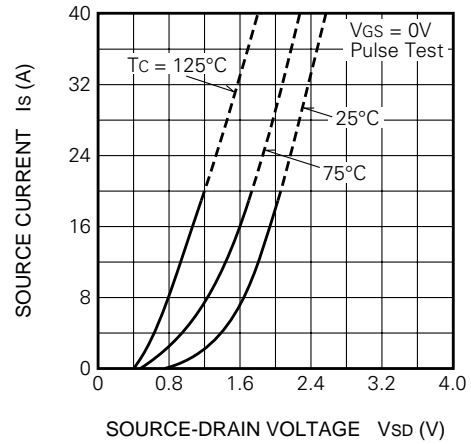
SWITCHING CHARACTERISTICS (TYPICAL)



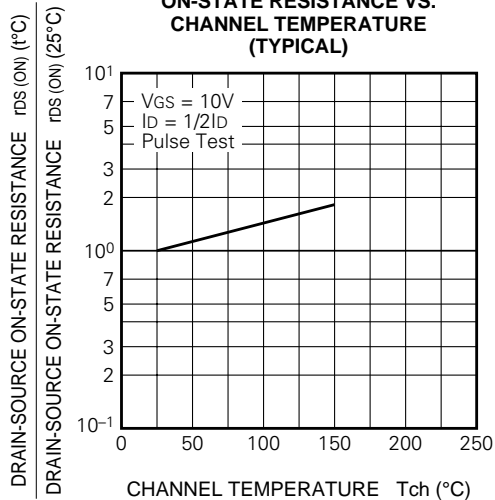
GATE-SOURCE VOLTAGE VS. GATE CHARGE (TYPICAL)



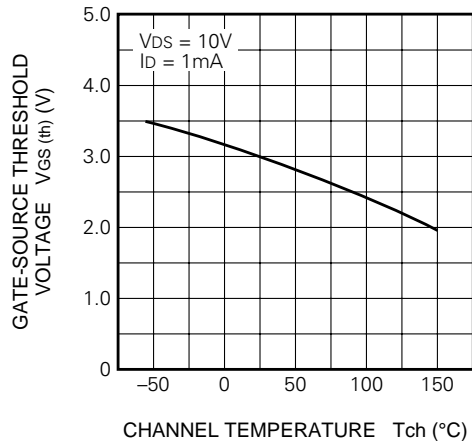
SOURCE-DRAIN DIODE FORWARD CHARACTERISTICS (TYPICAL)



ON-STATE RESISTANCE VS. CHANNEL TEMPERATURE (TYPICAL)



THRESHOLD VOLTAGE VS. CHANNEL TEMPERATURE (TYPICAL)



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HIGH-SPEED SWITCHING USE

